NSN 5961-01-299-8457

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-299-8457 **Inclosure Material:** Metal **Overall Length:** 1.252 inches **Overall Height:** Between 0.250 inches and 0.340 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact-darlington connected **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Burn in **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 collector to emitter voltage/static/base open and 60.0 collector to base voltage/static/emitter open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 80.00 milliamperes source cutoff current and 4.00 amperes source cutoff current **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No